

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LV5072M — DC/DC Converter IC

Overview

The SANYO LV5072M is a DC/DC converter IC that has a step-down DC/DC converter output and an externally-controllable GPO output for discharging the output capacitor.

Features

- One channel of synchronous rectifying PWM controlled step-down DC/DC converter output (0.8V to 3.3V/2A)
- One channel of externally controllable GPO output for discharging the output capacitor
- Built-in thermal shutdown circuit
- Built-in hiccup recovery

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{IN}	V _{IN} , PV _{IN}	-0.3 to 6.0	V
Input pin voltage	V _{IN} C	GPI, ENDCO	-0.3 to 6.0	V
Output pin voltage	V _{OUT}	LX, GPO	-0.3 to 6.0	V
Allowable Power dissipation	Pd max	Ta = 25°C Mounted on a circuit board.*	1.5	W
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-40 to +125	°C

^{*} Specified circuit board: 50.0mm × 50.0mm × 1.6mm, 2-layer glass epoxy printed circuit board, Wiring density on the backside = 54%

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Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{IN}	$V_{IN} = PV_{IN}, 0.8V \le V_{OUT} \le 1.3V$	2.95 to 5.5	V
		$V_{IN} = PV_{IN}, 1.3V \le V_{OUT} \le 1.9V$	3.2 to 5.5	V
		$V_{IN} = PV_{IN}, 1.9V \le V_{OUT} \le 3.3V$	4.5 to 5.5	V
Input pin voltage	V _{IN} C	GPI, ENDCO	-0.3 to V _{IN}	V

Electrical Characteristics, Current drain, unless otherwise specified at Ta = 25°C, $V_{IN} = 5.0$ V, no load

Doromotor	Symbol	Canditions	Ratings			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Standby current drain	I _{CC} SB	GPI = ENDCO = Low		0.5	10	μА
Current drain DCDC ON	I _{CC} FL	GPI = ENDCO = High, V _{OUT} = 1.8V		12	16	mA

DC/DC, unless otherwise specified at Ta = 25°C, $V_{IN} = 5.0$ V, $V_{OUT} = 1.8$ V, no load

Devemeter	Cumbal	Conditions	Ratings			Unit	
Parameter	Symbol Conditions		min	typ	max		
FB voltage	VFB	I _O = 10mA	0.49	0.50	0.51	V	
Current limit peak value	CLIMIT		2.3			Α	
Efficiency 1	EF1	I _O = 0.5A, V _{OUT} = 3.3V		90		%	
Efficiency 2	EF2	I _O = 0.5A, V _{OUT} = 1.8V		82		%	
Load regulation	VL	I _O = 1mA to 2A		25	70	mV	
Frequency	Fosc		1.7	2.2	2.7	MHz	
LX ON resistance	RLXP	I _O H = -300mA, Pch		0.15		Ω	
	RLXN	I _O L = 300mA, Nch		0.15		Ω	

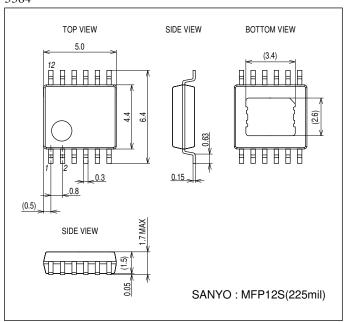
GPI, ENDCO Input, GPO Output, unless otherwise specified at Ta = 25 °C, $V_{IN} = 5.0$ V

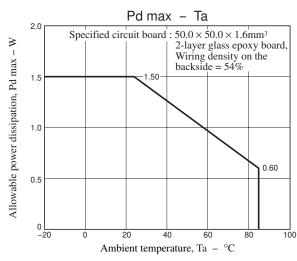
Parameter	Cumbal	O and distance	Ratings			Unit
Parameter	Symbol	Conditions	min	typ	max	Ullit
GPO Output current	Igpo	GPI = 0V, GPO = 1.5V	7.5	15	37.5	mA
GPO output voltage Low-level	V _O L	$GPI = 0V, I_OL = 5mA$		0.5	1	V
GPO output leakage current	ILK	GPO		0	10	μΑ
GPI/ENDCO input voltage High-level	V _{IN} H	Input High-level GPI, ENDCO	1.5			V
GPI/ENDCO input voltage Low-level	V _{IN} L	Input Low-level GPI, ENDCO	0		0.3	V

Package Dimensions

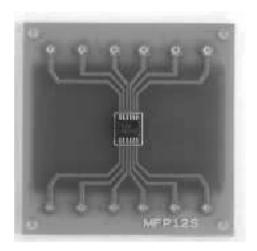
unit: mm (typ)

3384

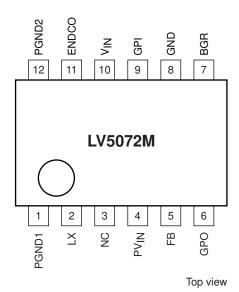




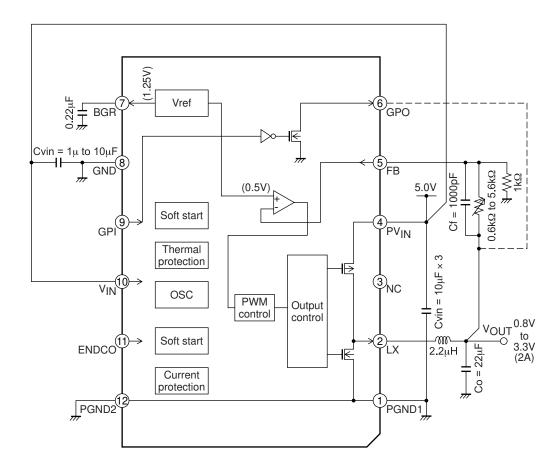
Specified board for Pd max measurement



Pin Assignment



Block Diagram



Pin Descriptions

Pin No.	Pin name	Description			
1	PGND1	DC/DC power-dedicated ground			
2	LX	ritching regulator PWM output pin			
3	NC	NC NC			
4	PVIN	DC/DC power dedicated power pin			
5	FB	DC/DC feedback voltage input pin			
6	GPO	O output for discharging the output capacitor			
7	BGR	ernal reference voltage output pin			
8	GND	nal ground			
9	GPI	PO output control pin. L: Output capacitor discharge			
10	V _{IN}	ignal system power supply			
11	ENDCO	DC/DC output control pin. Low : OFF, High : ON			
12	PGND2	DC/DC power dedicated ground			

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Pin Functions

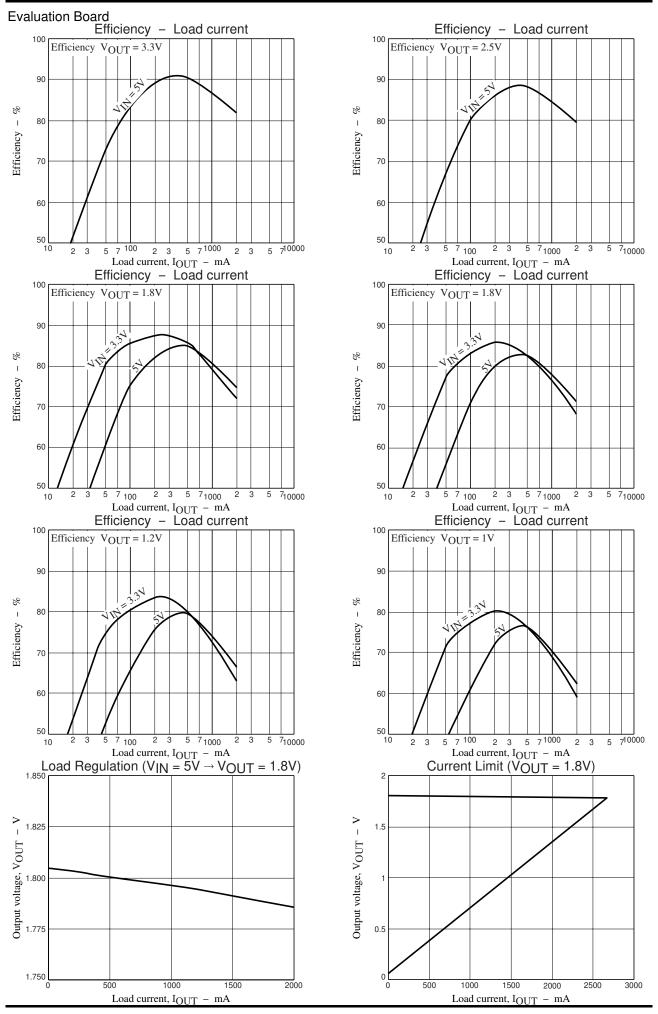
Pin No.	Pin Name	Pin function	Equivalent Circuit
2	LX	Switching regulator PWM signal output	PVIN C
			PGND O
5	FB	Switching regulator Feedback voltage input	NIN O
			FB W 1kΩ
			GND O
6	GPO	GPO output for discharging the output capacitor	GPO → 100Ω
7	BGR	Reference voltage output	GND O
			BGR 1.5kΩ

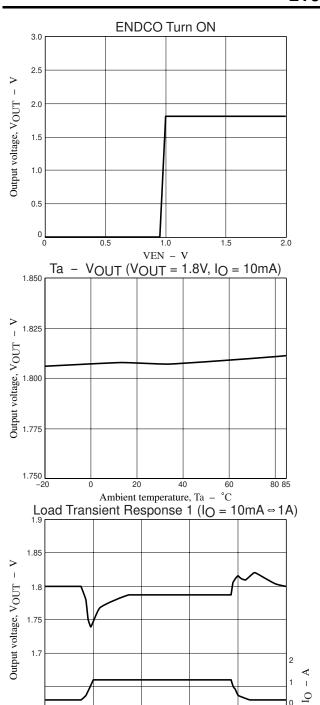
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in No.	Pin Name	Pin function	Equivalent Circuit
9	GPI	GP0 output control pin (Low : Discharging the output capacitor)	V _{IN} O
			GPI 10kΩ GY OS
			GND
11	ENDCO	DC/DC on/off control (High : Converter ON)	V _{IN} O
			ENDCO 10kΩ Gy00g
			GND O



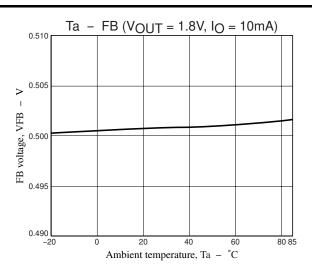


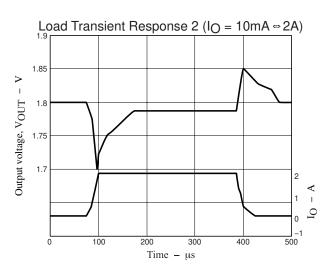
200

Time – μs

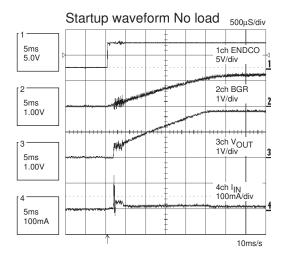
400

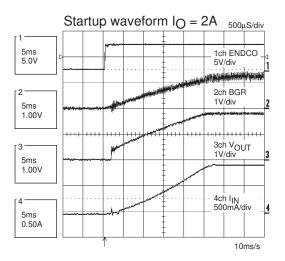
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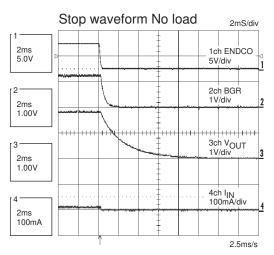


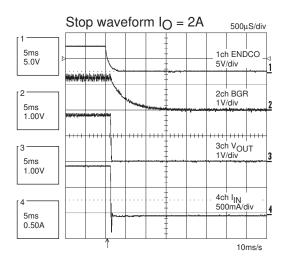


ENDCO ON Waveforms. (VOUT = 1.8V, Co = 22μ F, Cvin = 1μ F, Cpvin = 10μ F × 3, CBGR = 0.22μ F)









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